



UZ0107

TRIAC

LOGIC LEVEL FOUR-QUADRANT TRIAC

DESCRIPTION

The UTC **UZ0107** is a logic level four-quadrant triac, it uses UTC's advanced technology to provide customers with enhanced current surge capability and high blocking voltage, etc.

The UTC **UZ0107** is suitable for low power AC Fan controllers, industrial process control and general purpose low power motor control, etc.

FEATURES

* $I_{GT} \leq 5\text{mA}$, $I_{GT} \leq 10\text{mA}$ (T2- G+), $I_{TSM} \leq 12.5\text{A}$ ($t_p = 20\text{ms}$)

$I_{TSM} \leq 13.8\text{A}$ ($t_p = 16.7\text{ms}$), $I_{T(RMS)} \leq 1\text{A}$

* Enhanced current surge capability

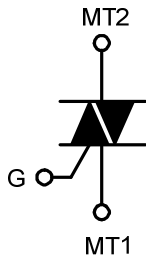
* Direct interfacing to logic level ICs

* High blocking voltage of 800V

* Enhanced noise immunity

* Sensitive gate in four quadrants

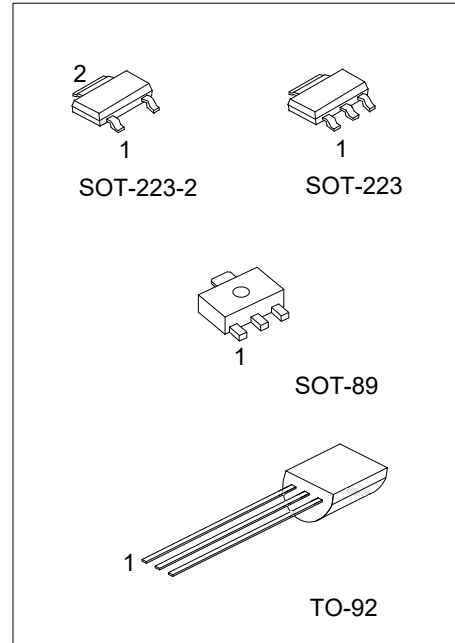
SYMBOL



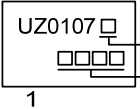
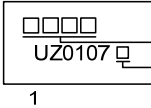
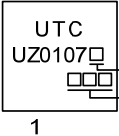
ORDERING INFORMATION

Ordering Number		Package	Pin Assignment			Packing
Lead Free	Halogen Free		1	2	3	
UZ0107L-x-AA2-R	UZ0107G-x-AA2-R	SOT-223-2	MT1	MT2	GATE	Tape Reel
UZ0107L-x-AA3-R	UZ0107G-x-AA3-R	SOT-223	MT1	MT2	GATE	Tape Reel
UZ0107L-x-AB3-R	UZ0107G-x-AB3-R	SOT-89	MT1	MT2	GATE	Tape Reel
UZ0107L-x-T92-B	UZ0107G-x-T92-B	TO-92	MT1	GATE	MT2	Tape Box
UZ0107L-x-T92-K	UZ0107G-x-T92-K	TO-92	MT1	GATE	MT2	Bulk

UZ0107G-x-AA2-R	(1) Packing Type	(1) R: Tape Reel, B: Tape Box, K: Bulk
	(2) Package Type	(2) AA2: SOT-223, AA3: SOT-223, AB3: SOT-89
	(3) Peak Voltage	T92: TO-92
	(4) Green Package	(3) 6: 600V, 8: 800V
		(4) G: Halogen Free and Lead Free, L: Lead Free



■ MARKING

PACKAGE	MARKING
SOT-223-2 SOT-223	 L: Lead Free G: Halogen Free Date Code
SOT-89	 Date Code L: Lead Free G: Halogen Free
TO-92	 L: Lead Free G: Halogen Free Date Code

■ ABSOLUTE MAXIMUM RATINGS

PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT
Repetitive Peak Off-State Voltage	V_{DRM}/V_{RRM}	Full Sine Wave, $T_{SP} \leq 103^{\circ}\text{C}$			600	V
					800	V
Non-Repetitive Peak On-State Current	I_{TSM}	Full Sine Wave, $T_{J(\text{init})} = 25^{\circ}\text{C}$, $t_p = 20\text{ms}$			12.5	A
		Full Sine Wave, $T_{J(\text{init})} = 25^{\circ}\text{C}$, $t_p = 16.7\text{ms}$			13.8	A
RMS On-State Current	$I_{T(RMS)}$	Full Sine Wave, $T_{SP} \leq 103^{\circ}\text{C}$			1	A
Peak Gate Current	I_{GM}				1	A
Peak Gate Power	P_{GM}				2	W
Average Gate Power	$P_{G(AV)}$	Over Any 20ms Period			0.1	W
Junction Temperature	T_J				125	$^{\circ}\text{C}$
Storage Temperature	T_{STG}		-40		+150	$^{\circ}\text{C}$
I^2t for Fusing	I^2t	$t_p = 10\text{ms}$, Sine-Wave Pulse			0.78	A^2s
Rate of Rise Of On-State Current	di/dt	$I_T = 1\text{A}$, $I_G = 20\text{mA}$, $di_G/dt = 100\text{mA}/\mu\text{s}$, T2+ G+			50	$\text{A}/\mu\text{s}$
		$I_T = 1\text{A}$, $I_G = 20\text{mA}$, $di_G/dt = 100\text{mA}/\mu\text{s}$, T2+ G-			50	$\text{A}/\mu\text{s}$
		$I_T = 1\text{A}$, $I_G = 20\text{mA}$, $di_G/dt = 100\text{mA}/\mu\text{s}$, T2- G-			50	$\text{A}/\mu\text{s}$
		$I_T = 1\text{A}$, $I_G = 20\text{mA}$, $di_G/dt = 100\text{mA}/\mu\text{s}$, T2- G+			20	$\text{A}/\mu\text{s}$

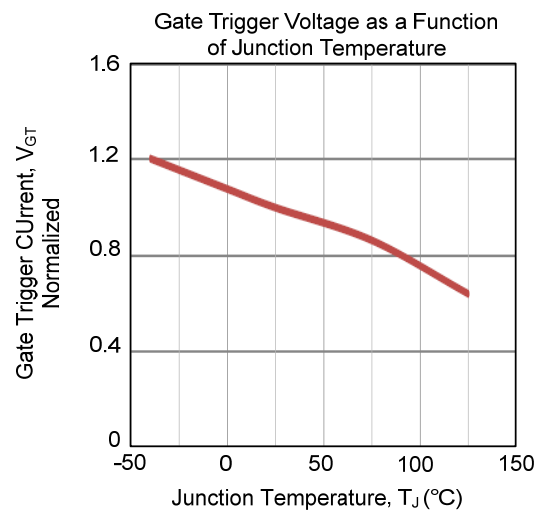
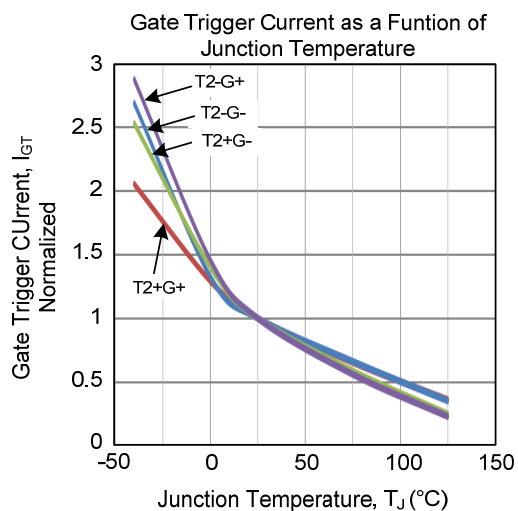
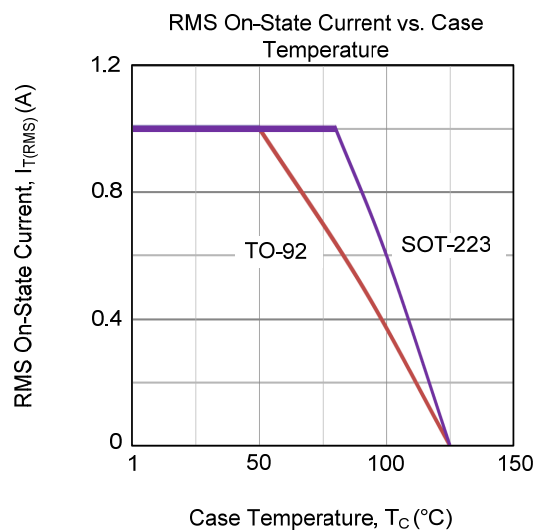
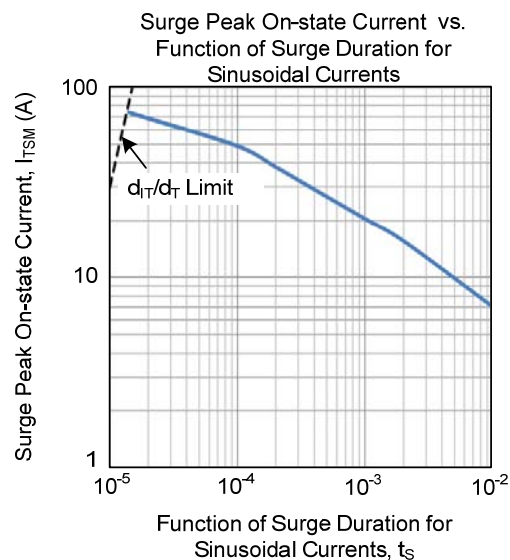
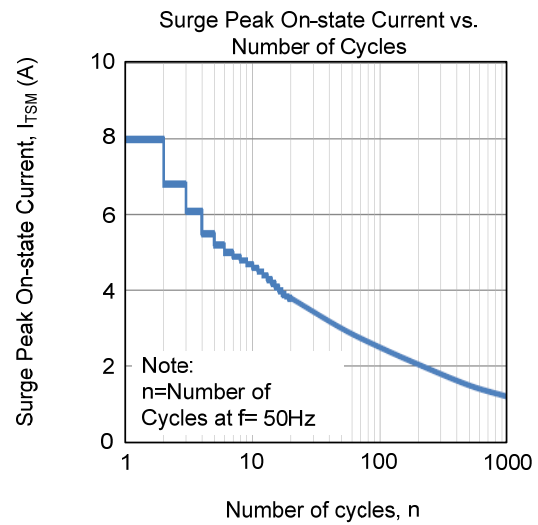
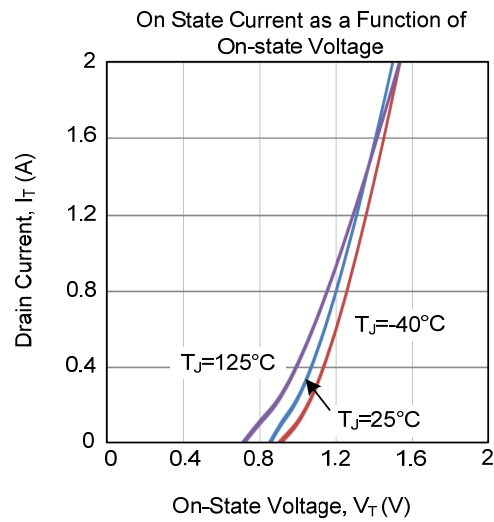
■ THERMAL DATA

PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT
Thermal Resistance from Junction to Solder Point	θ_{J-SP}	Full Cycle			15	K/W
Thermal resistance from junction to lead	θ_{J-Lead}				6	K/W
Thermal Resistance from Junction to Ambient	SOT-223-2	θ_{JA}		156		K/W
	SOT-223			70		K/W
	SOT-89			200		K/W
	TO-92			150		K/W

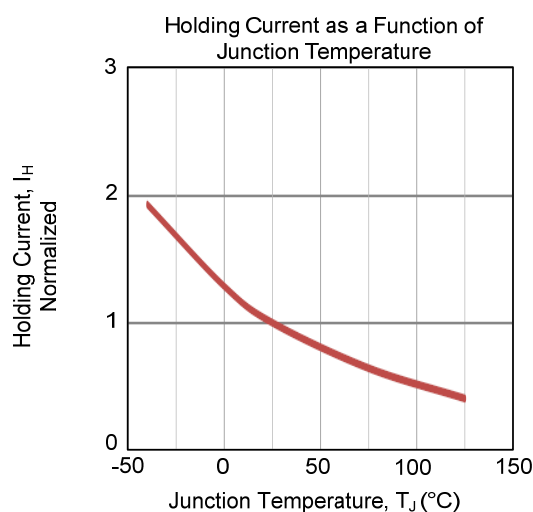
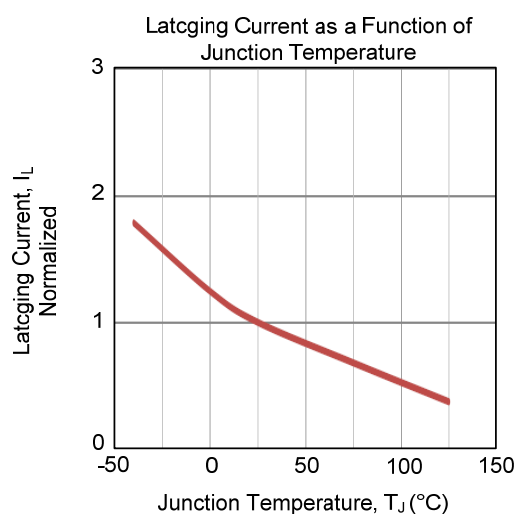
■ ELECTRICAL CHARACTERISTICS

PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT
Gate Trigger Current ($T_J=25^{\circ}\text{C}$)	I_{GT}	$V_D=12\text{V}$, $I_T=0.1\text{A}$, T2+ G+	0.3		5	mA
		$V_D=12\text{V}$, $I_T=0.1\text{A}$, T2+ G-	0.3		5	mA
		$V_D=12\text{V}$, $I_T=0.1\text{A}$, T2- G-	0.3		5	mA
		$V_D=12\text{V}$, $I_T=0.1\text{A}$, T2- G+	0.3		10	mA
Latching Current ($T_J=25^{\circ}\text{C}$)	I_L	$V_D=12\text{V}$, $I_G=0.1\text{A}$, T2+ G+			10	mA
		$V_D=12\text{V}$, $I_G=0.1\text{A}$, T2+ G-			25	mA
		$V_D=12\text{V}$, $I_G=0.1\text{A}$, T2- G-			10	mA
		$V_D=12\text{V}$, $I_G=0.1\text{A}$, T2- G+			10	mA
Holding Current	I_H	$V_D=12\text{V}$, $T_J=25^{\circ}\text{C}$			10	mA
On-State Voltage	V_T	$I_T=1\text{A}$, $T_J=25^{\circ}\text{C}$		1.3	1.6	V
Gate Trigger Voltage	V_{GT}	$V_D=12\text{V}$, $I_T=0.1\text{A}$, $T_J=25^{\circ}\text{C}$			1.3	V
		$V_D=V_{DRM}=\text{Rated } V_{DRM}$ and V_{RRM} $I_T=0.1\text{A}$, $T_J=125^{\circ}\text{C}$	0.2			V
Off-State Current	I_D	$V_D=V_{DRM}=\text{Rated } V_{DRM}$ and V_{RRM} $R_{GK}=1\text{k}\Omega$, $T_J=125^{\circ}\text{C}$			0.5	mA
Rate of Rise of Off-State Voltage	dV_D/dt	$V_{DM}=402\text{V}$, $T_J=110^{\circ}\text{C}$, Gate Open Circuit	100			V/ μs
Rate of Change of Commutating Voltage	dV_{com}/dt	$V_{DM}=400\text{V}$, $T_J=110^{\circ}\text{C}$, $dI_{com}/dt=0.44\text{A/ms}$, Gate Open Circuit	0.5			V/ μs

TYPICAL CHARACTERISTICS



■ TYPICAL CHARACTERISTICS (Cont.)



UTC assumes no responsibility for equipment failures that result from using products at values that exceed, even momentarily, rated values (such as maximum ratings, operating condition ranges, or other parameters) listed in products specifications of any and all UTC products described or contained herein. UTC products are not designed for use in life support appliances, devices or systems where malfunction of these products can be reasonably expected to result in personal injury. Reproduction in whole or in part is prohibited without the prior written consent of the copyright owner. UTC reserves the right to make changes to information published in this document, including without limitation specifications and product descriptions, at any time and without notice. This document supersedes and replaces all information supplied prior to the publication hereof.